Normal-Conducting Photoinjector for High Power CW FEL

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An RF photoinjector capable of producing high continuous average current with low emittance and energy spread is a key enabling technology for high power CW FEL. The design of a 2.5-cell, π -mode, 700-MHz normal-conducting RF photoinjector cavity with magnetic emittance compensation is completed. With average gradients of 7, 7, and 5 MV/m in its three accelerating cells, the photoinjector will produce a 2.5-MeV electron beam with 3-nC charge per bunch and transverse rms emittance below 7 mm-mrad.

Electromagnetic modeling has been used extensively to optimize ridge-loaded tapered waveguides and RF couplers, and led to a new, improved coupler iris design. The results, combined with a thermal and stress analysis, show that the challenging problem of cavity cooling can be successfully solved. Fabrication of a demo 100-mA (at 35 MHz bunch repetition rate) photoinjector is underway. The design is scalable to higher average currents by increasing the electron bunch repetition rate, and provides a path to a MW-class amplifier FEL.



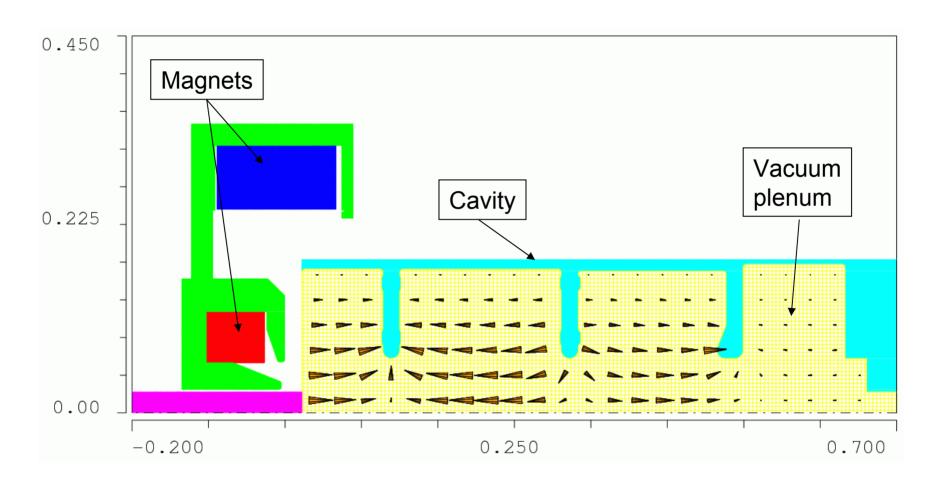


Normal-Conducting RF Photoinjector

- Requirements and parameters:
 - CW, 700-MHz RF; emittance < 10 mm·mrad at the wiggler
 - 3 nC per bunch, 100 mA at 35-MHz bunch rep rate (→ 1 A)
- Design:
 - split cavities: 2.5-cell PI (old 777 design: 7,7,7 MV/m, 2.70 MeV
 → new 775 design: 7,7,5 MV/m, 2.54 MeV)
 + booster (4 cells, 4.5 MV/m, 5.5 MeV)
 - PI: 2.5 cells, emittance-compensated, on-axis electric coupling
 - 100 mA: P_w (668 kW) + P_b (254 kW) \rightarrow 1 A: 668 kW + 2540 kW
- EM modeling: cavity, RF couplers, and ridge-loaded tapered waveguides
- Beam dynamics TS2 versus Parmela
- Thermal & stress analysis, manufacturing → AES, Medford, NY



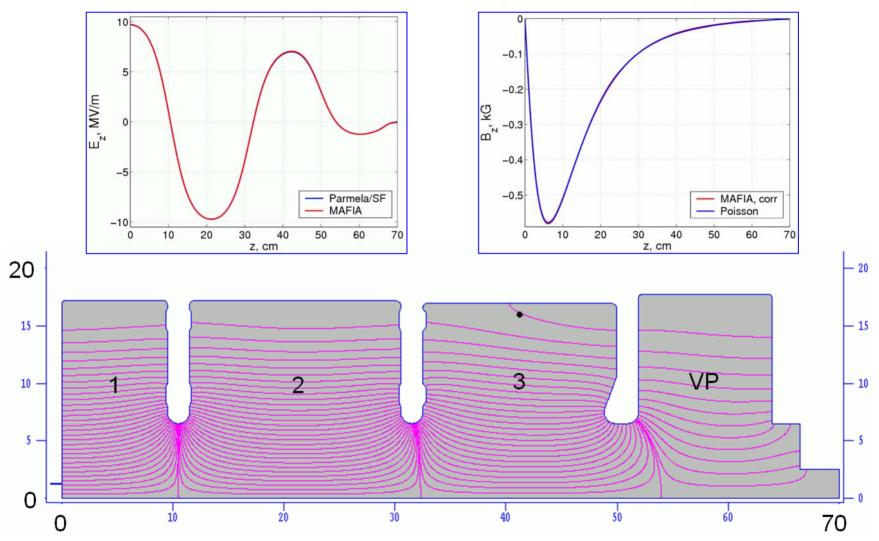
2.5-cell RF Photoinjector Cavity



MAFIA model of 2.5-cell cavity with magnets and vacuum plenum



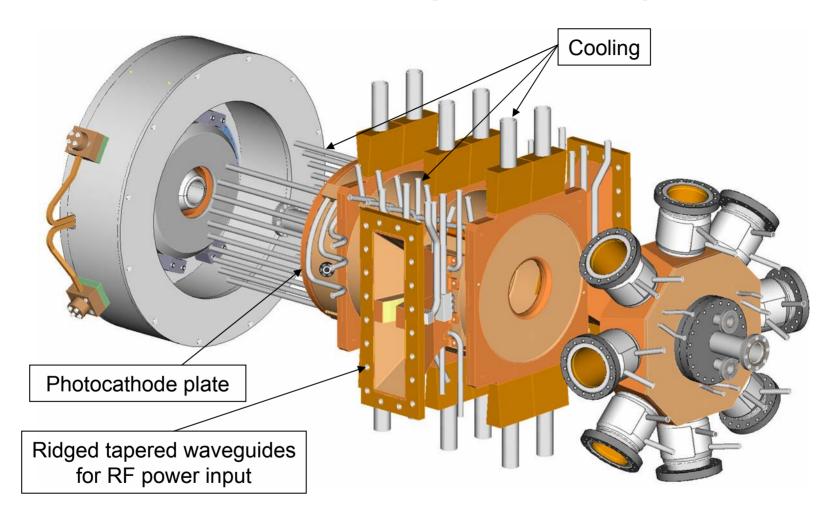
2.5-cell RF Photoinjector Cavity



2.5-cell PI with vacuum plenum – SF & MAFIA results



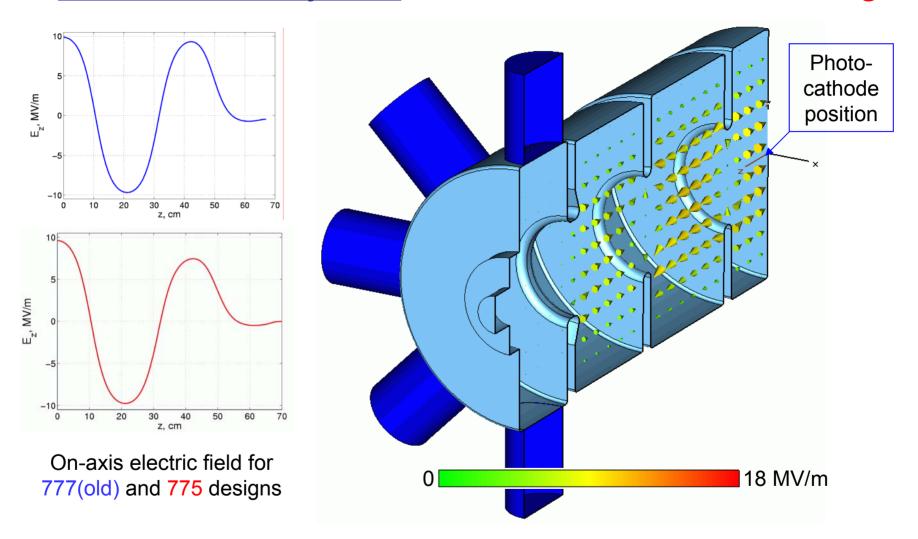
Normal-Conducting RF Photoinjector



2.5-cell PI with emittance-compensating magnets (left) and vacuum plenum (right)



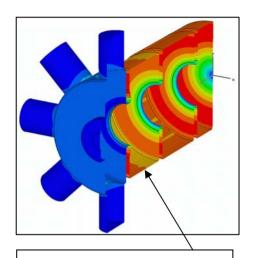
NC RF Photoinjector: Microwave Studio Modeling



Electric field of π -mode in 2.5-cell cavity: $E_0=7$ MV/m in cells 1&2, 5 MV/m in cell 3.



NC RF Photoinjector: Microwave Studio Modeling



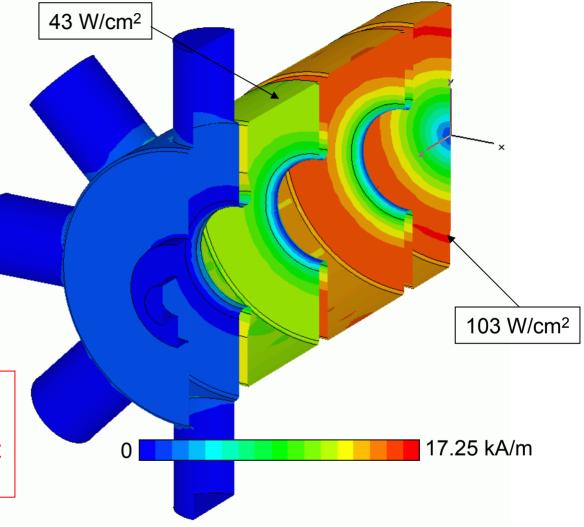
For comparison: in the old (777) design 75 W/cm² in 3rd cell

Power in the 775 design:

 $P_w = 668 \text{ kW} \text{ versus}$

 $P_b = 254 \text{ kW for } 100 \text{ mA, but}$

 P_b = 2540 kW for 1 A

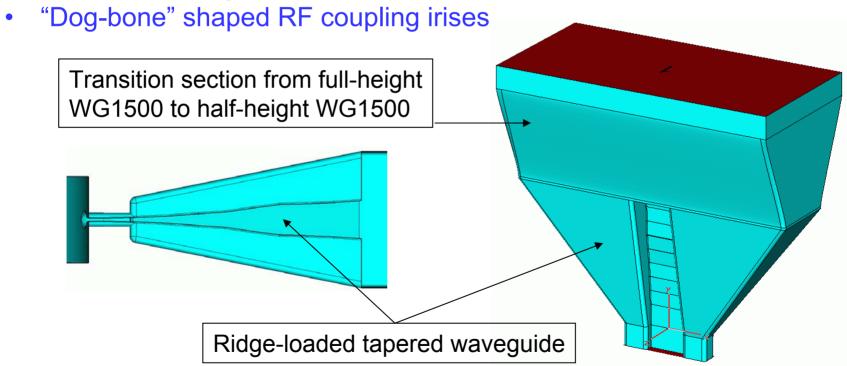


Surface current distribution for the π -mode in 2.5-cell photoinjector cavity (775)

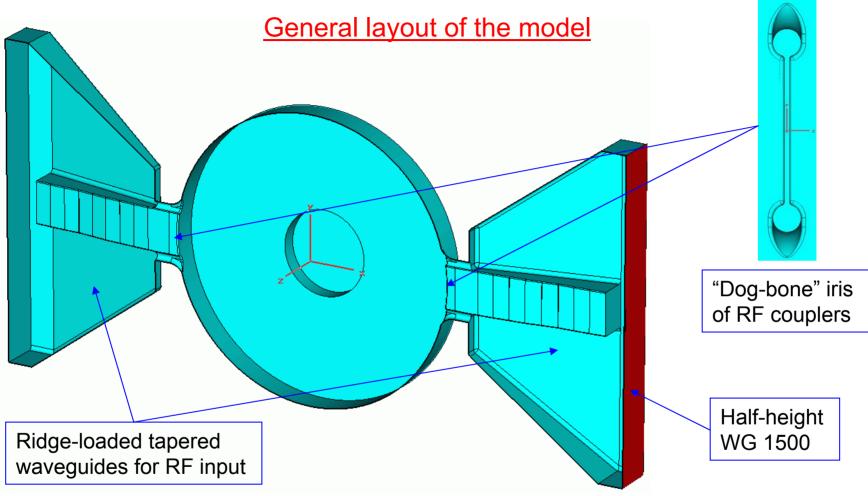


RF Power for NC Photoinjector

- 922 kW of RF input power for 100 mA beam current:
 - CW, 700-MHz RF power is fed through two waveguides
- Ridge-loaded tapered waveguides (RLWG)
 - Design is based on LEDA RFQ and SNS power couplers
 - Ridge profile is found by SF calculations for cross sections (LY), and checked using MicroWave Studio (MWS) 3-D calculations



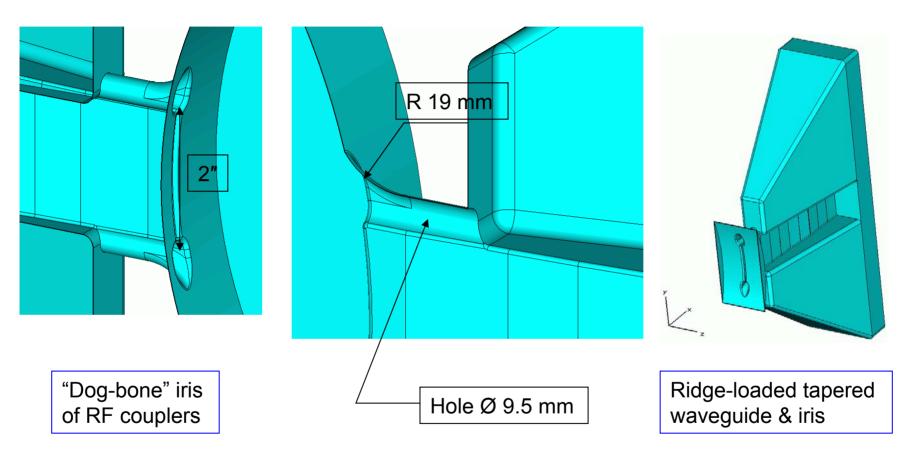




RF coupler model. Tapered ridge-loaded waveguides are coupled to the 3rd cell of photoinjector cavity (modeled here by a pillbox) via irises cut through thick walls.



Details of coupler irises



RF coupler model. Details of coupler irises and ridge-loaded tapered waveguides. The wall thickness near the iris is 1.2", the iris gap width is 1.8 mm.



Procedure

For 100 mA, the required WG-cavity coupling is $\beta_c = \frac{P_w + P_b}{P_w} = 1.38$.

For the pillbox model, the required coupling is $\beta_{pb} = \beta_c \frac{W_c}{W_{pb}} \left(\frac{H_{pb}}{H_c}\right)^2 \frac{Q_{pb}}{Q_c}$.

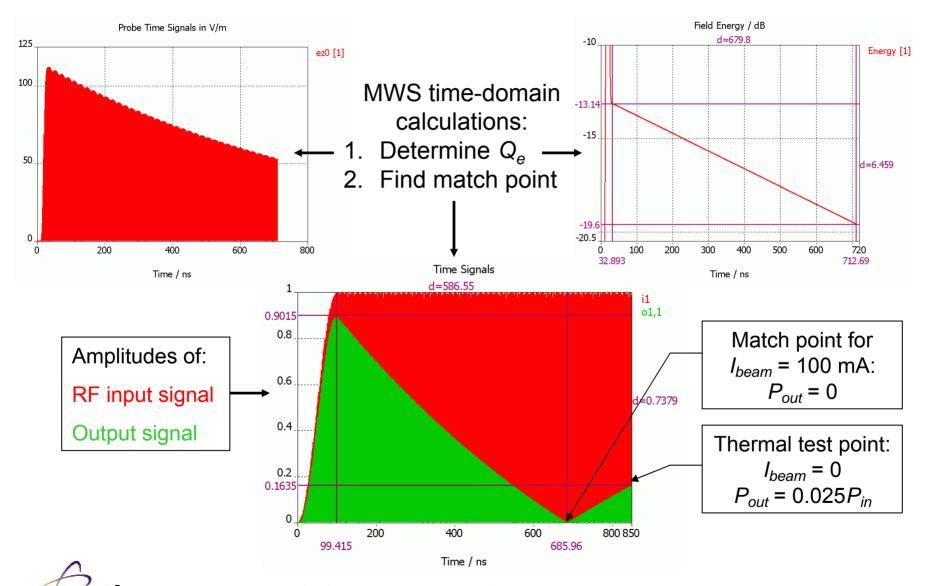
Then the required Q_e for the model is $Q_e = \frac{Q_c}{\beta_c} \frac{W_{pb}}{W_c} \left(\frac{H_c}{H_{pb}} \right)^2 = 1933$.

We calculate Q_e in the model directly using time-domain simulations with MicroWave Studio (MWS), and adjust the coupling. After that, again in MWS, an RF signal with a constant amplitude is fed into waveguides to find the match point (P_{out} = 0), and calculate the field and surface power distributions at the match.

S.S. Kurennoy, L.M. Young. "RF Coupler for High-Power CW FEL Photoinjector", PAC2003, p. 3515.



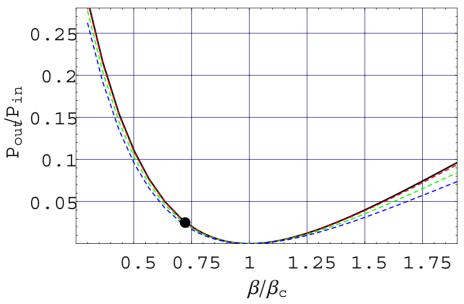
EM Modeling of RF Coupler: Time Domain (TD)



From energy balance $P_{in} - P_{out} = P_w + P_b \equiv \beta P_w$ one can find power ratio

$$\frac{P_{out}}{P_{in}} = 1 - \frac{\beta}{\beta_c} f\left(\alpha, \frac{\beta}{\beta_c}\right), \text{ where } f(\frac{1}{y}, x) = \left(\frac{1 + y\sqrt{1 + (y^2 - 1)x}}{1 + y^2 x}\right)^2.$$

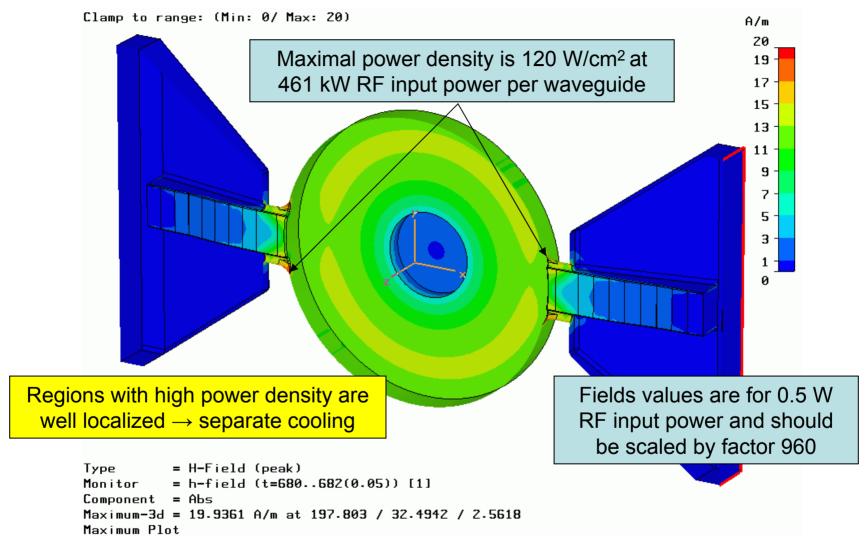
Coefficient $0 < \alpha < 1$ is the amplitude ratio of the input and reflected waves, $1-\alpha << 1$. For $\beta = 1$, $\beta_c = 1.38$, ratio $P_{out}/P_{in} \approx 0.025$, practically independent of value of α .



For
$$\alpha = 1$$
,
 $(1-x)^2/(1+x)^2$;
 $\alpha = 0.99$;
 $\alpha = 0.95$;
 $\alpha = 0.90$.



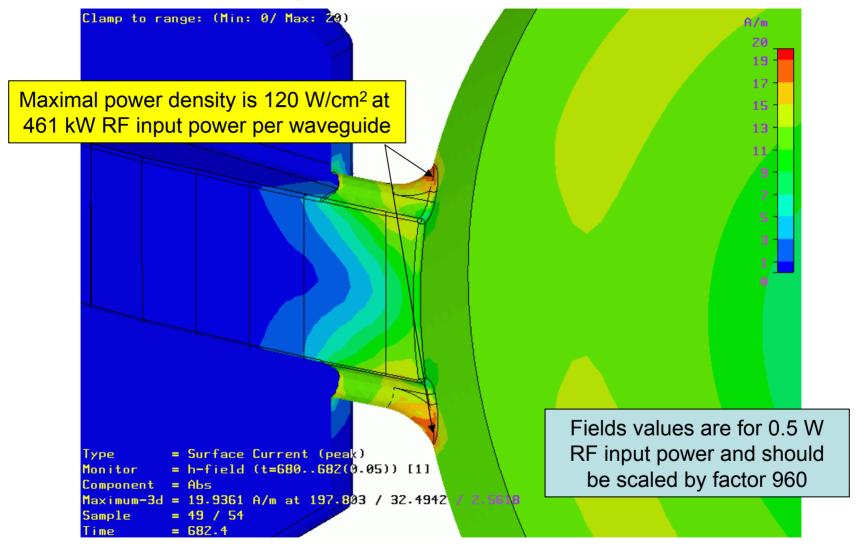
EM Modeling of RF Coupler: TD Results



Surface magnetic fields at the match point from MWS time-domain simulations



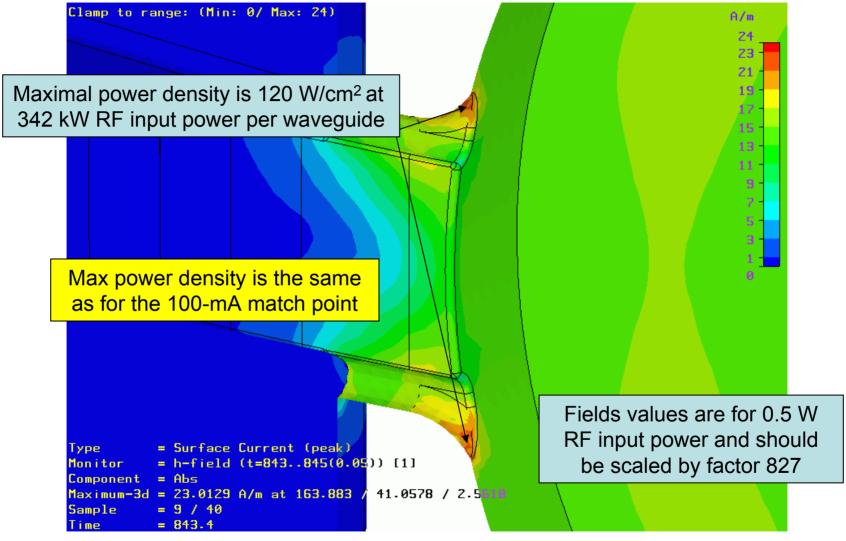
EM Modeling of RF Coupler: TD Results



Surface currents near the irises at the match from MWS time-domain simulations



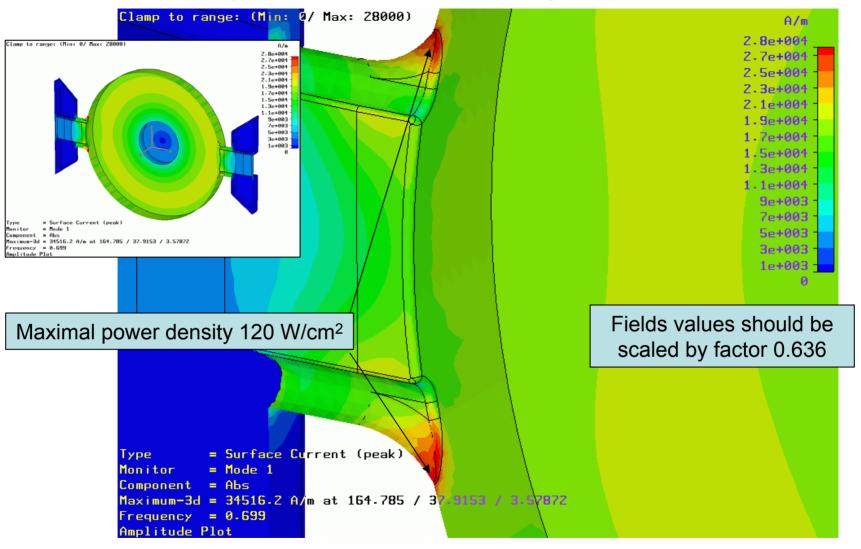
EM Modeling of RF Coupler: TD Results



Surface currents near the irises at thermal-test point (no beam, 2.5% reflection)



EM Modeling of RF Coupler: Eigensolver X-check



Surface currents from MWS eigensolver calculations (mesh 3.006M for 1/8)



EM Modeling of RF Coupler: Results for 775

MWS time domain

Mesh, K points	Max <i>dP/ds</i> , W/cm ²
111	107
111*	104*
312	120
312*	119*
760	114
760*	114*

MWS eigensolver

Mesh, K points	Max <i>dP/ds</i> , W/cm ²
86	95
201	109
734	120
1539	122
3006	118

Compare to 43 W/cm² at smooth wall in the 3^{rd} cell far from irises: power ratio is < $2.8 \rightarrow$ field enhancement due to irises is < 1.65

For 777 design max *dP/ds* was 220 W/cm²

For reference: in the LEDA RFQ couplers max $dP/ds \approx 150 \text{ W/cm}^2$, while the power ratio (max / smooth wall) was about 10

Maximal values of surface power density from MWS calculations



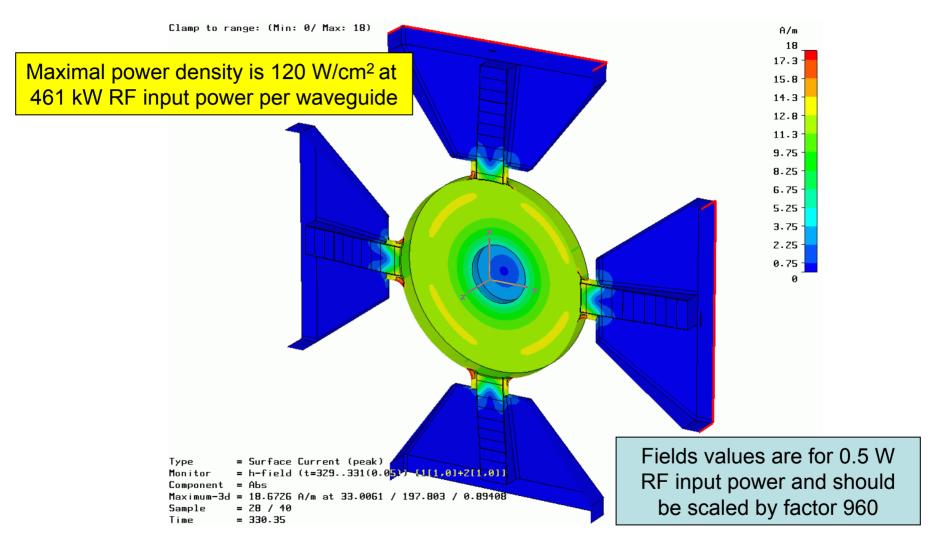
^{*} W/o beam, 342 kW per WG (incl. 2.5% reflection)

NC Photoinjector, RF Couplers: Summary

- 100-mA operation of normal conducting photoinjector requires almost 1 MW of CW 700-MHz RF power that will be fed through two ridge-loaded tapered waveguides.
- RF coupler design is based on LEDA RFQ and SNS couplers. The coupler-cavity system is modeled using a novel approach with direct MWS time-domain simulations. Results for the maximal power density are checked using eigensolvers.
- The coupler design is optimized using 3-D EM modeling to reduce the maximal surface power density on the coupler irises:
 - Increased hole radius and wall thickness; blended iris edges;
 - Field enhancement is only 65% compared to smooth cavity walls.
- In the 775 PI cavity, the max power density near the irises is only 15% higher than max in the smooth cavity. This design reduces stresses and facilitates cavity cooling. Thermal management is still challenging but feasible.
- The PI cavity is being manufactured by AES. Its thermal tests with full RF load are scheduled at LANL (LEDA) in early 2006.

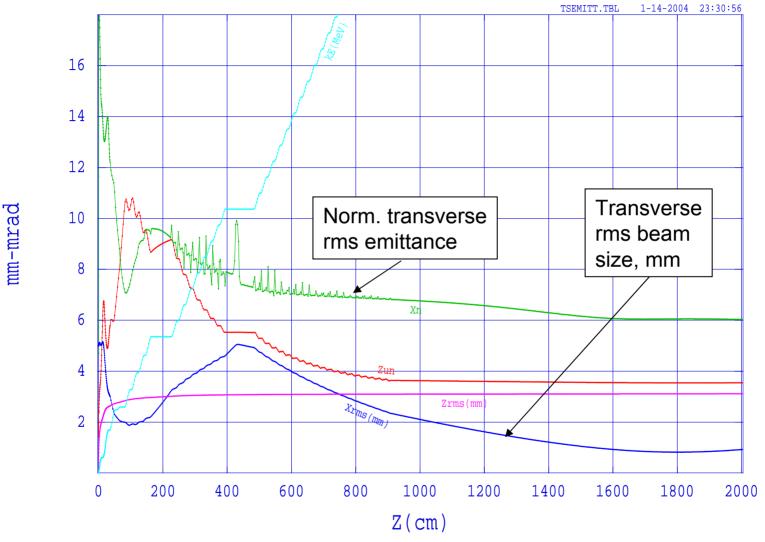


RF Cavity Model with 4 RLWG: Matched at 0.46 A



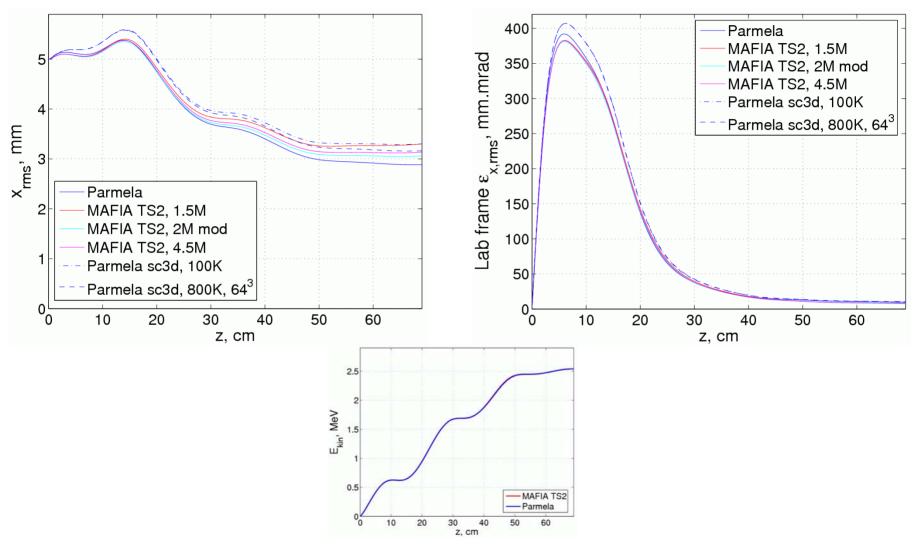
Surface currents at the match point from MWS time-domain simulations



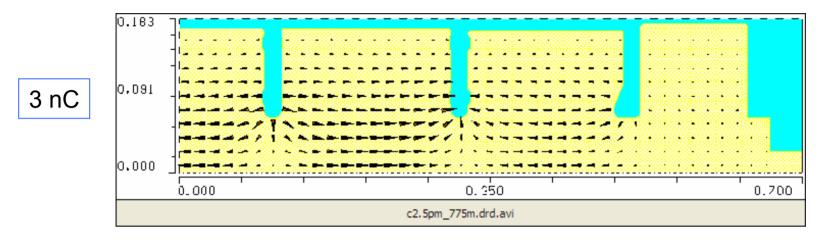


Parmela simulations of 2.5-cell PI + booster + linac (L. Young)









0.183

0.001

0.001

0.000

0.000

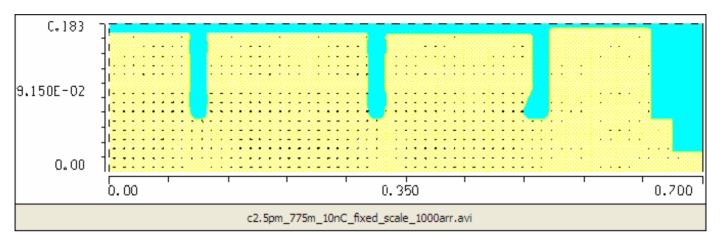
0.250

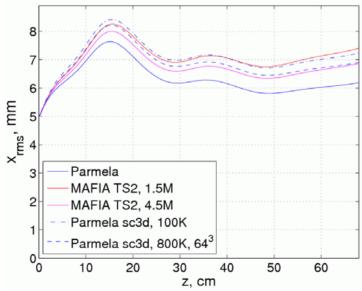
0.700

MAFIA TS2 simulations of 2.5-cell PI (wake fields included)



10 nC, *E*-scale is fixed





MAFIA TS2 simulations of 2.5-cell PI: 10-nC bunch charge



Beam dynamics in photoinjector: Summary

- 100-mA operation of the normal-conducting 700-MHz CW photoinjector requires 3-nC bunches at 35-MHz bunch repetition rate. Higher currents are achievable with higher bunch repetition rates.
- Beam dynamics in the PI RF cavity is modeled using Parmela and MAFIA TS2 particle-in-cell (PIC) simulations. Results for 3 nC are in agreement.
- Wake fields effects are weak, even for 10 nC per bunch. TS2 simulations with multiple bunches at 350-MHz repetition rate show identical parameters of bunches at the cavity exit.
- The PI cavity is being fabricated by AES. Its thermal tests with full RF load are scheduled at LANL (LEDA facility) in early 2006.

